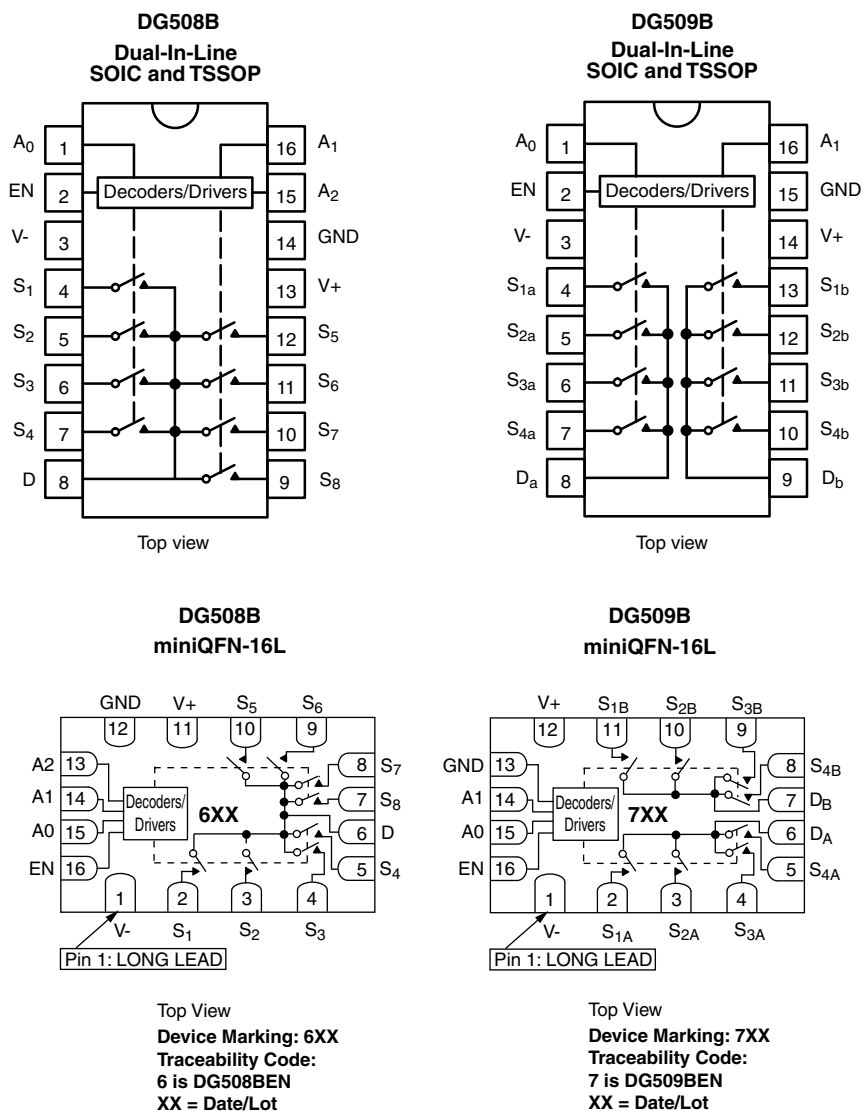


FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION

TRUTH TABLES AND ORDERING INFORMATION

TRUTH TABLE (DG508B)				
A ₂	A ₁	A ₀	EN	ON SWITCH
X	X	X	0	None
0	0	0	1	1
0	0	1	1	2
0	1	0	1	3
0	1	1	1	4
1	0	0	1	5
1	0	1	1	6
1	1	0	1	7
1	1	1	1	8

TRUTH TABLE (DG509B)			
A ₁	A ₀	EN	ON SWITCH
X	X	0	None
0	0	1	1
0	1	1	2
1	0	1	3
1	1	1	4

Logic "0" = V_{IL} ≤ 0.8 V

Logic "1" = V_{IH} ≥ 2 V

X = Do not care

**ORDERING INFORMATION (DG508B)**

TEMP. RANGE	PACKAGE	PART NUMBER
-40 °C to +125 °C ^a	16-Pin SOIC	DG508BEY-T1-E3
	16-Pin TSSOP	DG508BEQ-T1-E3
	16-Pin PDIP	DG508BEJ-E3
	16-Pin MiniQFN	DG508BEN-T1-GE4

ORDERING INFORMATION (DG509B)

TEMP. RANGE	PACKAGE	PART NUMBER
-40 °C to +125 °C ^a	16-Pin SOIC	DG509BEY-T1-E3
	16-Pin TSSOP	DG509BEQ-T1-E3
	16-Pin PDIP	DG509BEJ-E3
	16-Pin MiniQFN	DG509BEN-T1-GE4

Note

a. -40 °C to +85 °C datasheet limits apply.

ABSOLUTE MAXIMUM RATINGS

PARAMETER		LIMIT	UNIT
Voltages Referenced to V-	V+	44	V
	GND	25	
Digital Inputs ^a , V _S , V _D		(V-) - 2 to (V+) + 2 or 20 mA, whichever occurs first	
Current (Any terminal)		30	mA
Peak Current, S or D (Pulsed at 1 ms, 10 % duty cycle max.)		100	
Storage Temperature	(EY, EQ, EJ, EN suffix)	-65 to +150	°C
Power Dissipation (Packages) ^b	16-Pin Narrow SOIC ^c	600	mW
	16-Pin TSSOP ^d	450	
	16-Pin PDIP ^e	510	
	16-Pin miniQFN ^f	525	
Thermal Resistance (θJA) ^b	16-Pin Narrow SOIC ^c	125	°C/W
	16-Pin TSSOP ^d	178	
	16-Pin PDIP ^e	159.6	
	16-Pin miniQFN ^f	152	

Notes

- Signals on SX, DX or INX exceeding V+ or V- will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- All leads soldered or welded to PC board.
- Derate 8 mW/°C above 70 °C.
- Derate 5.6 mW/°C above 70 °C.
- Derate 6.3 mW/°C above 70 °C.
- Derate 6.6 mW/°C above 70 °C.



SPECIFICATIONS

PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V+ = 15 V, V- = -15 V (± 10 %) VAX, VEN = 2 V, 0.8 V ^a		TEMP. ^b	TYP. ^c	-40 °C to +125 °C		-40 °C to +85 °C		UNIT	
						MIN. ^d	MAX. ^d	MIN. ^d	MAX. ^d		
Analog Switch											
Analog Signal Range ^e	VANALOG			Full	-	-15	15	-15	15	V	
Drain-Source On-Resistance	RDS(on)	VD = ± 10 V, IS = -1 mA		Room	180	-	380	-	380	Ω	
				Full	-	-	480	-	450		
RDS(on) Matching	ΔRDS(on)	VD = ± 10 V		Room	10	-	-	-	-		
Source Off Leakage Current	IS(off)	VD = ± 10 V VS = ∓ 10 V VEN = 0 V		Room	-	-1	1	-1	1	nA	
				Full	-	-50	50	-50	50		
Drain Off Leakage Current	ID(off)			Room	-	-1	1	-1	1		
				Full	-	-100	100	-100	100		
				Room	-	-1	1	-1	1		
				Full	-	-50	50	-50	50		
Drain On Leakage Current	ID(on)	Room	-	-1	1	-1	1				
		Full	-	-100	100	-100	100				
		Room	-	-1	1	-1	1				
		Full	-	-50	50	-50	50				
Digital Control											
Logic High Input Voltage	VINH			Full	-	2	-	2	-	V	
Logic Low Input Voltage	VINL			Full	-	-	0.8	-	0.8		
Logic High Input Current	IIH	VAX, VEN = 2 V		Full	-	-1	1	-1	1	μA	
Logic Low Input Current	IIL	VAX, VEN = 0.8 V		Full	-	-1	1	-1	1		
Logic Input Capacitance ^e	CIN	f = 1 MHz		Room	4	-	-	-	-	pF	
Dynamic Characteristics											
Transition Time	tTRANS	VS1 = +10 V/-10 V, VS8 = -10 V/+10 V, RL = 1 MΩ, CL = 35 pF		Room	145	-	300	-	300	ns	
				Full	-	-	400	-	400		
Break-Before-Make Interval	tOPEN	VS1 = VS8 = 5 V, CL = 35 pF, RL = 1 kΩ		Room	37	15	-	15	-		
				Full	-	1	-	1	-		
Enable Turn-On Time	tON(EN)	VS1 = 5 V, VS2 to VS8 = 0 V, RL = 1 kΩ, CL = 35 pF		Room	100	-	250	-	250		
				Full	-	-	340	-	340		
Enable Turn-Off Time	tOFF(EN)			Room	90	-	240	-	240		
				Full	-	-	300	-	300		
Charge Injection ^e	QINJ	CL = 1 nF, RGEN = 0 W, VGEN = 0 V		Full	2	-	-	-	-	pC	
Off Isolation ^e	OIRR	CL = 5 pF, RL = 50 Ω, f = 1 MHz		Room	-81	-	-	-	-	dB	
Crosstalk ^e	XTALK			Room	-88	-	-	-	-		
-3 dB Bandwidth ^e	BW	RL = 50 Ω		Room	250	-	-	-	-	MHz	
Total Harmonic Distortion ^e	THD	RL = 10 kΩ, 5 Vrms f = 20 Hz to 20 kHz		Room	0.04	-	-	-	-	%	
Source Off Capacitance ^e	CS(off)	f = 1 MHz		Room	3	-	-	-	-	pF	
Drain Off Capacitance ^e	CD(off)			DG508B	Room	13	-	-	-		-
				DG509B	Room	8	-	-	-		-
Drain On Capacitance ^e	CD(on)			DG508B	Room	18	-	-	-		-
				DG509B	Room	11	-	-	-		-
Power Supply											
Positive Supply Current	I+	VAX, VEN = 0.8 V or 2.4 V		Room	0.01	-	0.2	-	0.2	mA	
				Full	-	-	0.3	-	0.3		
Negative Supply Current	I-			Full	0.06	-10	-	-10	-	μA	



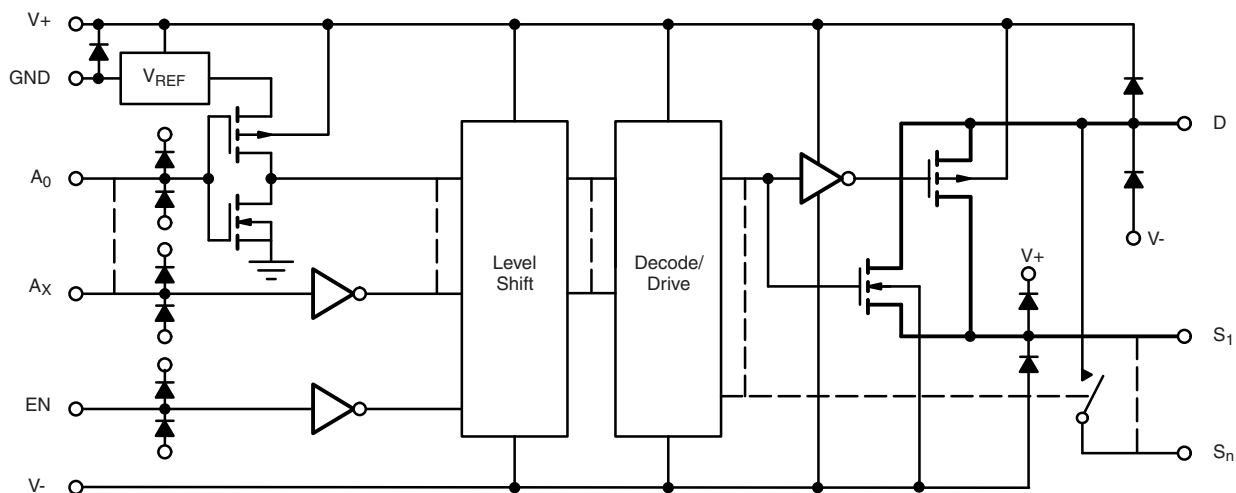
SPECIFICATIONS (Single Supply 12 V)											
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V+ = 12 V, V- = 0 V (± 10 %) VAX, VEN = 2 V, 0.8 V ^a		TEMP. ^b	TYP. ^c	-40 °C to +125 °C		-40 °C to +85 °C		UNIT	
						MIN. ^d	MAX. ^d	MIN. ^d	MAX. ^d		
Analog Switch											
Analog Signal Range ^e	VANALOG			Full	-	0	12	0	12	V	
On-Resistance	RDS(on)	VD = 10 V/0 V, IS = 1 mA		Room	265	-	500	-	500	Ω	
				Full	-	-	650	-	600		
RDS(on) Matching	ΔRDS(on)			Room	10	-	-	-	-		
Switch Off Leakage Current	IS(off)	V+ = 12 V, V- = 0 V VD = 0 V/10 V, VS = 10 V/0 V		DG508B	Room	-	-1	1	-1	1	nA
					Full	-	-50	-50	-50	50	
	ID(off)			DG508B	Room	-	-1	1	-1	1	
					Full	-	-100	100	-100	100	
	ID(off)			DG509B	Room	-	-1	1	-1	1	
					Full	-	-50	50	-50	50	
Channel On Leakage Current	ID(on)	V+ = 12 V, V- = 0 V VS = VD = 0 V/10 V		DG508B	Room	-	-1	1	-1	1	nA
					Full	-	-100	100	-100	100	
				DG509B	Room	-	-1	1	-1	1	
					Full	-	-50	50	-50	50	
Digital Control											
Logic High Input Voltage	VINH			Full	-	2	-	2	-	V	
Logic Low Input Voltage	VINL			Full	-	-	0.8	-	0.8		
Logic High Input Current	IIH	VAX, VEN = 2 V		Full	-	-1	1	-1	1	μA	
Logic Low Input Current	IIL	VAX, VEN = 0.8 V		Full	-	-1	1	-1	1		
Logic Input Capacitance ^e	CIN	f = 1 MHz		Room	4	-	-	-	-	pF	
Dynamic Characteristics											
Transition Time	tTRANS	VS1 = 10 V/0 V, VS8 = 0 V/10 V, RL = 1 MΩ, CL = 35 pF		Room	165	-	400	-	400	ns	
				Full	-	-	550	-	500		
Break-Before-Make Interval	tOPEN	VS1 = VS8 = 5 V, CL = 35 pF, RL = 1 kΩ		Room	37	15	-	15	-		
				Full	-	1	-	1	-		
Enable Turn-On Time	tON(EN)	VS1 = 5 V, VS2 to VS8 = 0 V, RL = 1 kΩ, CL = 35 pF		Room	125	-	300	-	300		
				Full	-	-	550	-	425		
Enable Turn-Off Time	tOFF(EN)			Room	75	-	250	-	250		
				Full	-	-	350	-	300		
Charge Injection ^e	QINJ	CL = 1 nF, RGEN = 0 Ω, VGEN = 0 V		Full	2.5	-	-	-	-	pC	
Off Isolation ^e	OIRR	CL = 5 pF, RL = 50 Ω f = 1 MHz		Room	-80	-	-	-	-	dB	
Crosstalk ^e	XTALK			Room	-88	-	-	-	-		
-3 dB Bandwidth ^e	BW	RL = 50 Ω		Room	200	-	-	-	-	MHz	
Total Harmonic Distortion ^e	THD	RL = 10 kΩ, 5 VRMS, f = 20 Hz to 20 kHz		Room	0.26	-	-	-	-	%	
Source Off Capacitance ^e	CS(off)	f = 1 MHz		Room	2	-	-	-	-	pF	
Drain Off Capacitance ^e	CD(off)				DG508B	13	-	-	-		-
					DG509B	8	-	-	-		-
Channel On Capacitance ^e	CD(on)				DG508B	17	-	-	-		-
					DG509B	12	-	-	-		-

SPECIFICATIONS (Single Supply 12 V)									
PARAMETER	SYMBOL	TEST CONDITIONS UNLESS OTHERWISE SPECIFIED V ₊ = 12 V, V ₋ = 0 V (± 10 %) V _{AX} , V _{EN} = 2 V, 0.8 V ^a	TEMP. ^b	TYP. ^c	-40 °C to +125 °C		-40 °C to +85 °C		UNIT
					MIN. ^d	MAX. ^d	MIN. ^d	MAX. ^d	
Power Supply									
Positive Supply Current	I+	V _{AX} , V _{EN} = 0.8 V or 2.4 V	Room	0.01	-	0.2	-	0.2	mA
			Full	-	-	0.3	-	0.3	

Notes

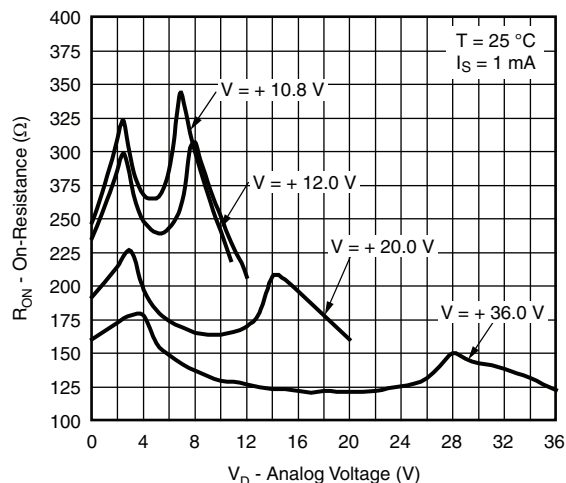
- V_{AX} , V_{EN} = input voltage perform proper function.
- Room = 25 °C, Full = as determined by the operating temperature suffix.
- Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this datasheet.
- Guaranteed by design, not subject to production test.
- $\Delta R_{DS(on)} = R_{DS(on)} \text{ max.} - R_{DS(on)} \text{ min.}$

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

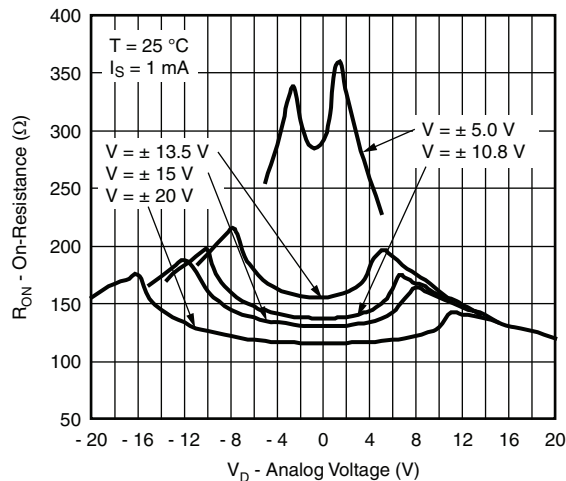
SCHEMATIC DIAGRAM (Typical Channel)

Fig. 1



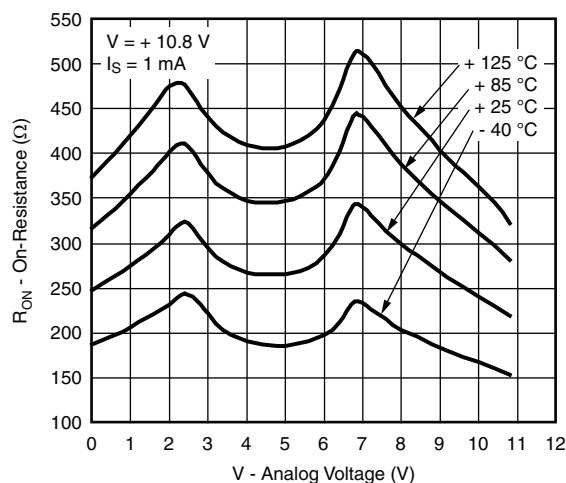
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



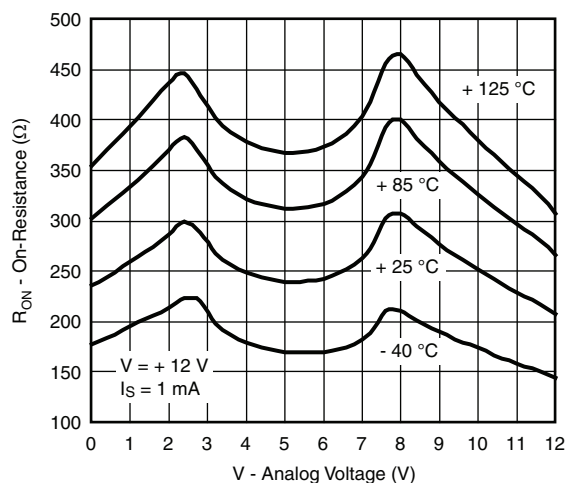
On-Resistance vs. V_D and Single Supply Voltage



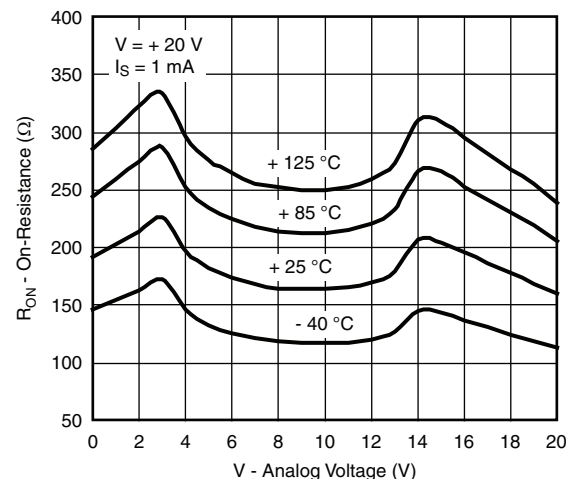
On-Resistance vs. V_D and Dual Supply Voltage



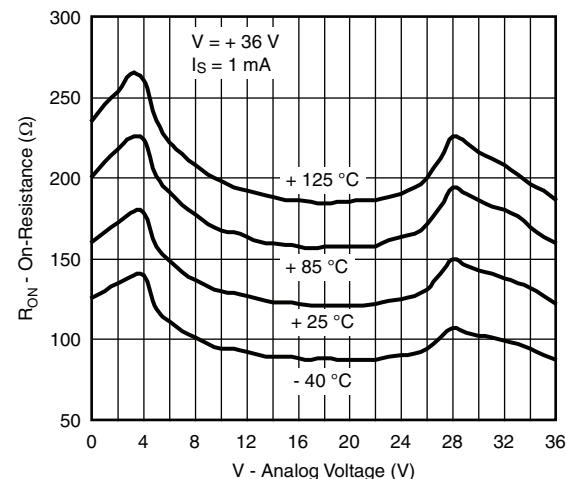
On-Resistance vs. Analog Voltage and Temperature



On-Resistance vs. Analog Voltage and Temperature



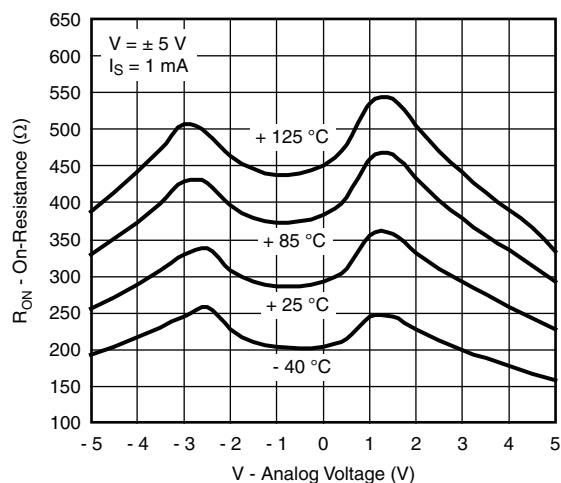
On-Resistance vs. Analog Voltage and Temperature



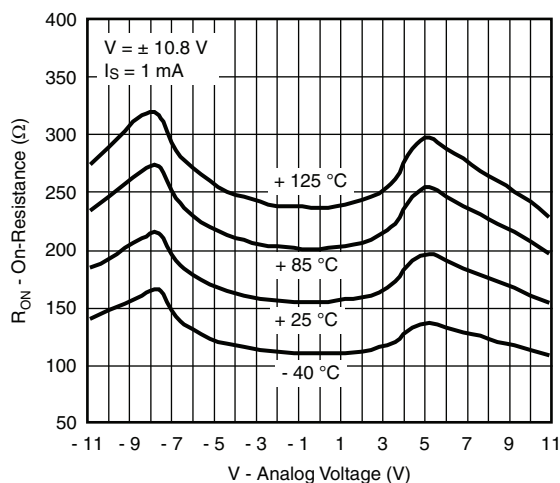
On-Resistance vs. Analog Voltage and Temperature



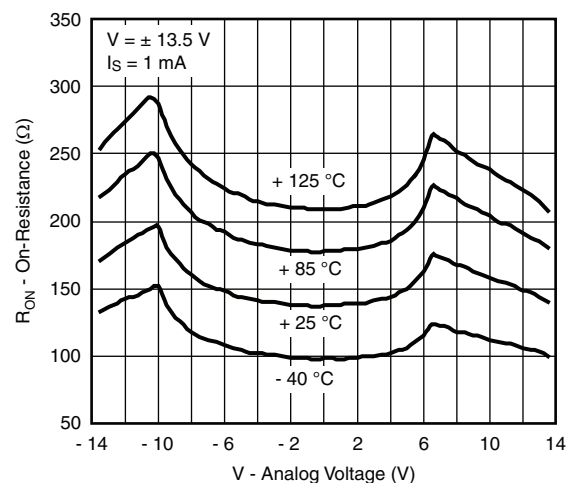
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



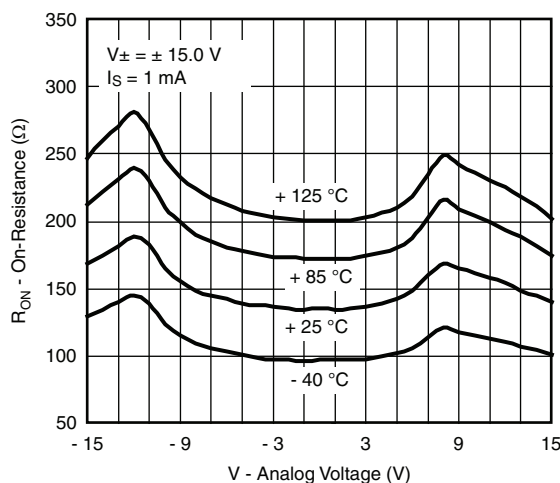
On-Resistance vs. Analog Voltage and Temperature



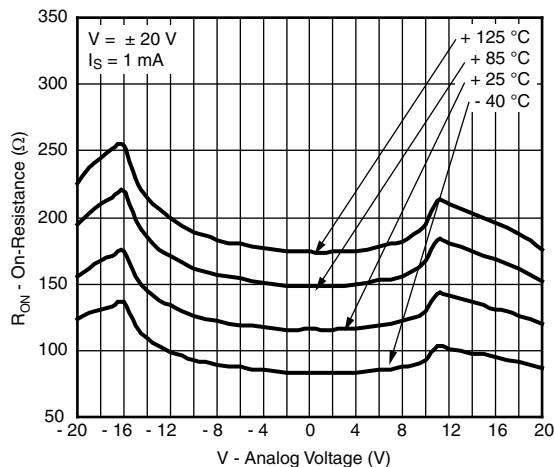
On-Resistance vs. Analog Voltage and Temperature



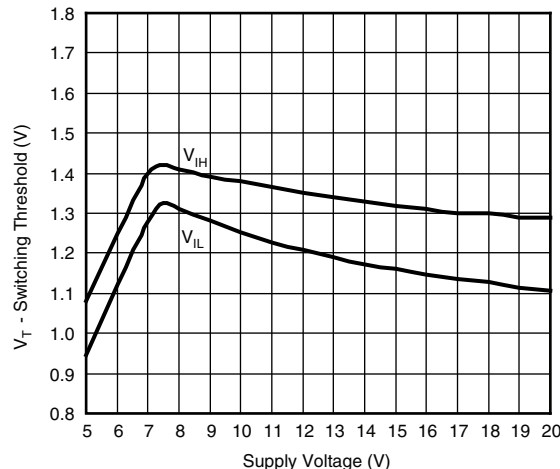
On-Resistance vs. Analog Voltage and Temperature



On-Resistance vs. Analog Voltage and Temperature



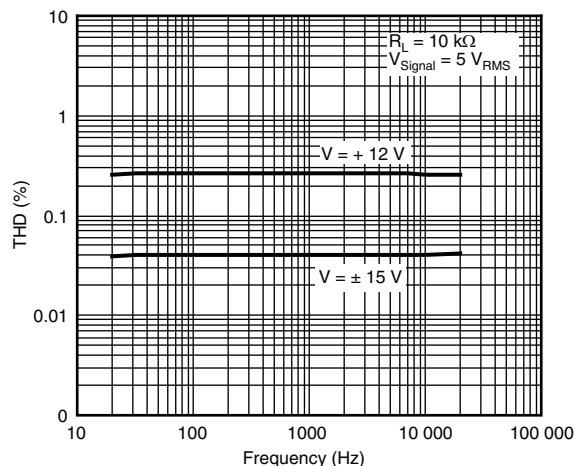
On-Resistance vs. Analog Voltage and Temperature



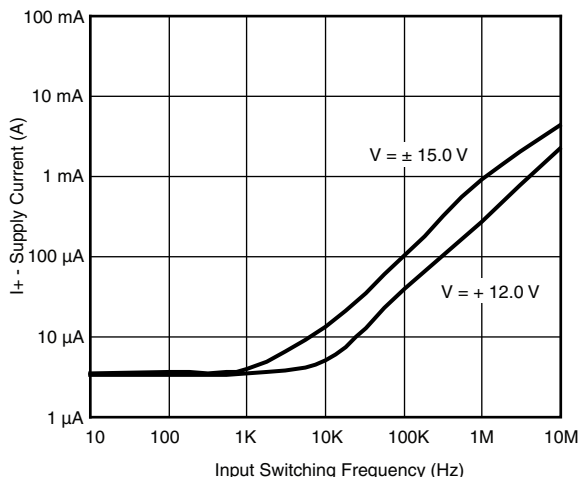
Switching Threshold vs. Supply Voltage



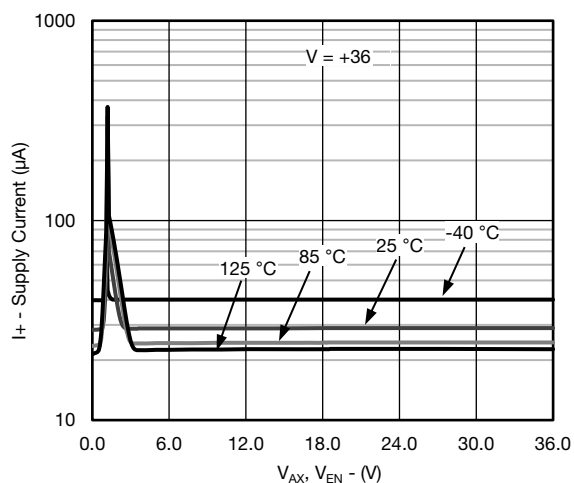
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



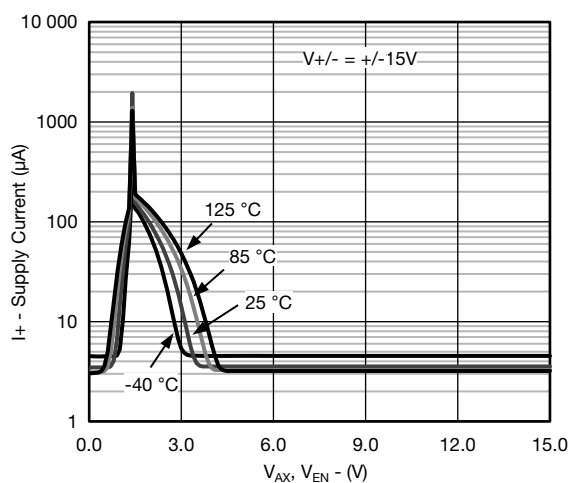
THD vs. Frequency



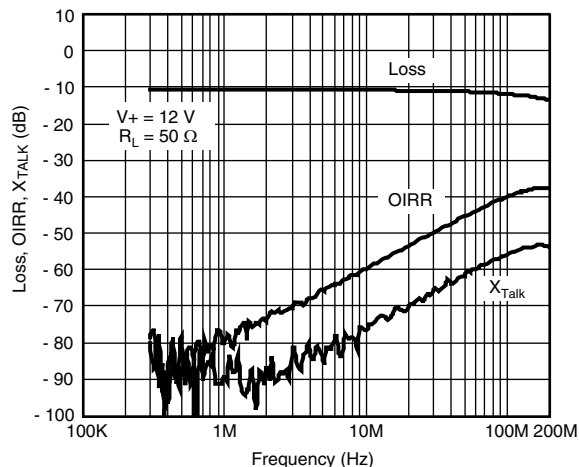
Supply Current vs. Input Switching Frequency



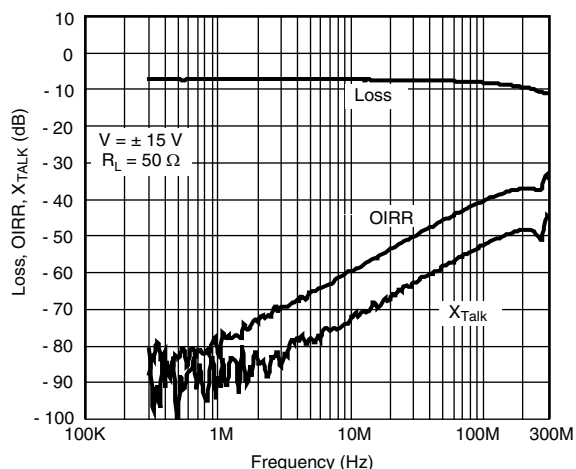
Supply Current vs. $V_{\text{AX}}, V_{\text{EN}}$



Supply Current vs. $V_{\text{AX}}, V_{\text{EN}}$



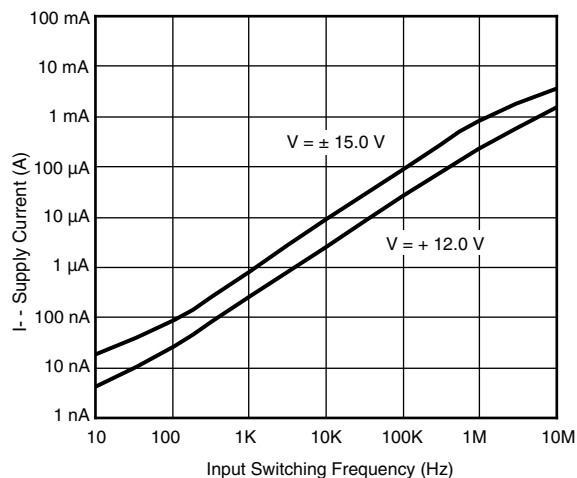
Insertion Loss, Off-Isolation, Crosstalk vs. Frequency



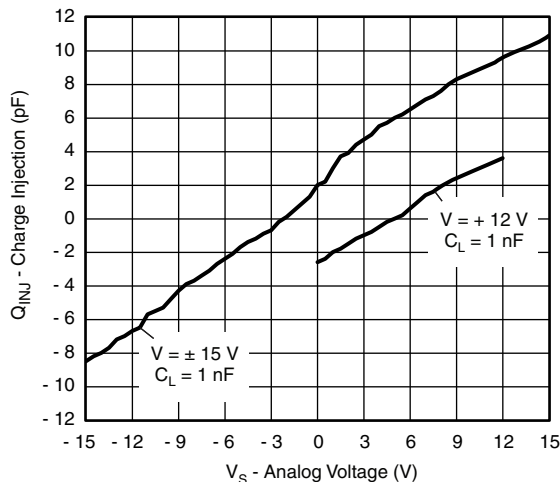
Insertion Loss, Off-Isolation, Crosstalk vs. Frequency



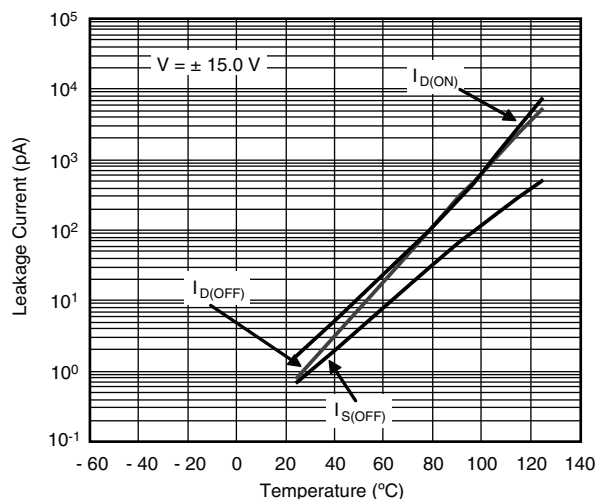
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



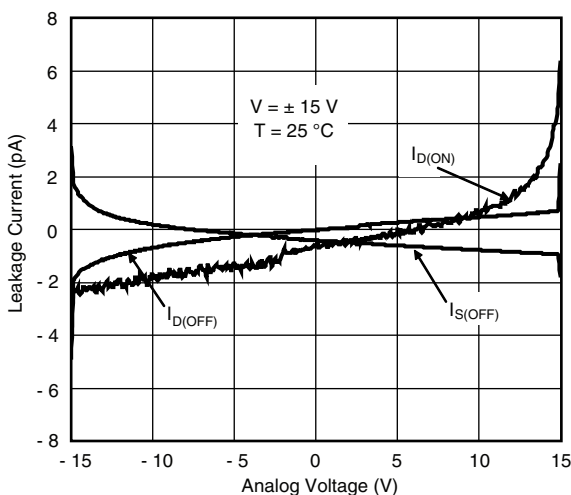
Supply Current vs. Input Switching Frequency



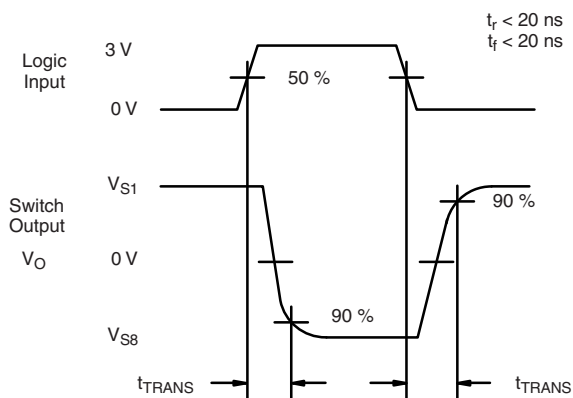
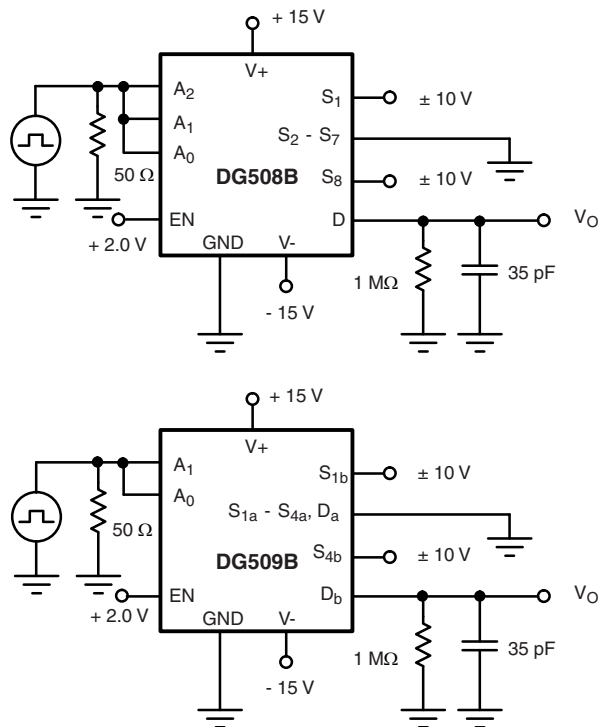
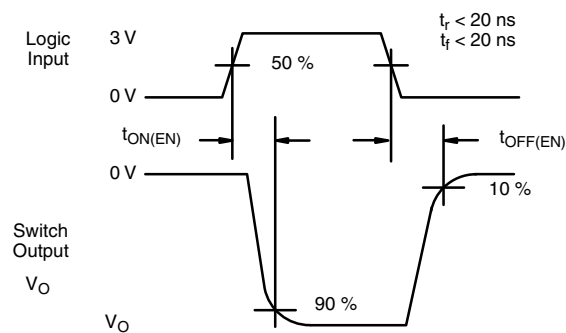
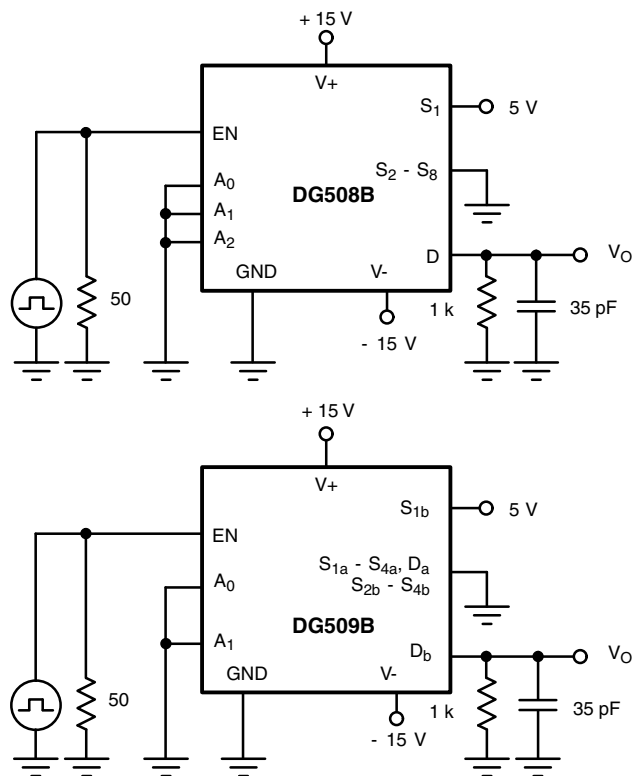
Charge Injection vs. Analog Voltage

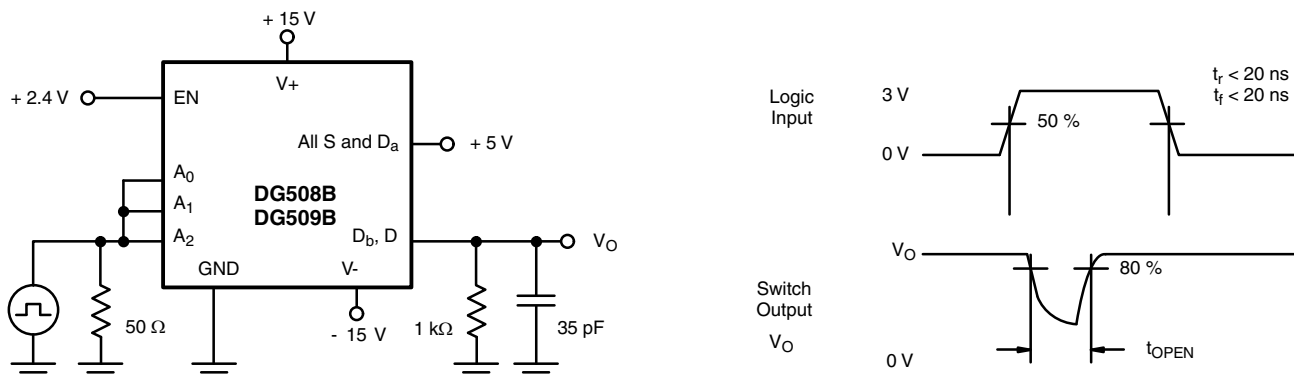
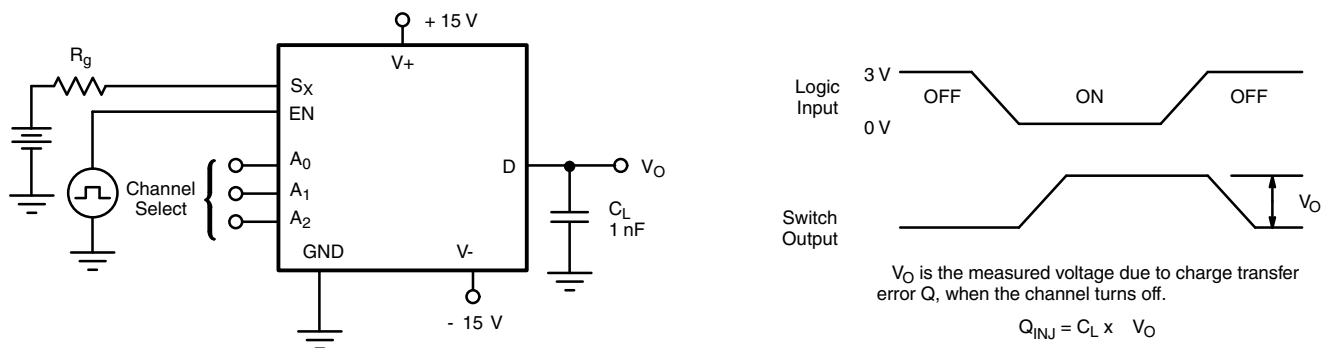
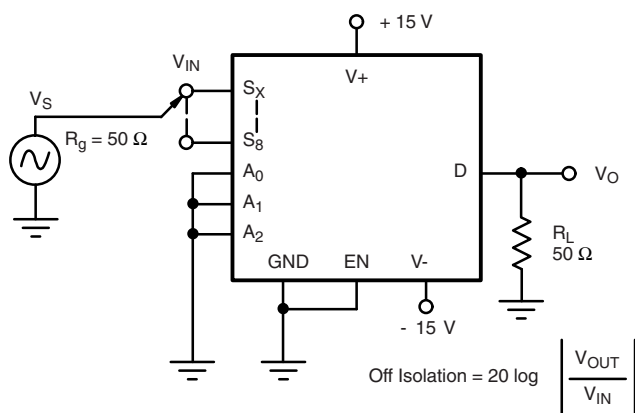
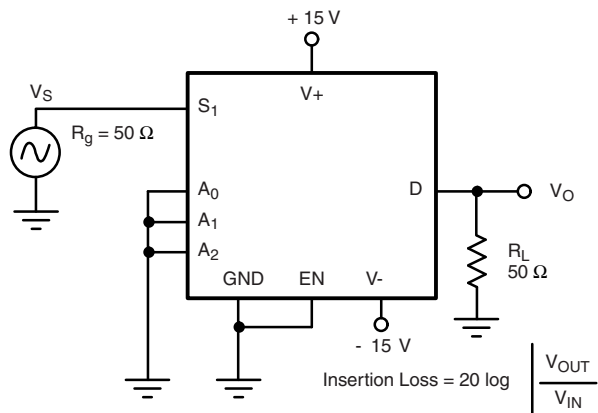


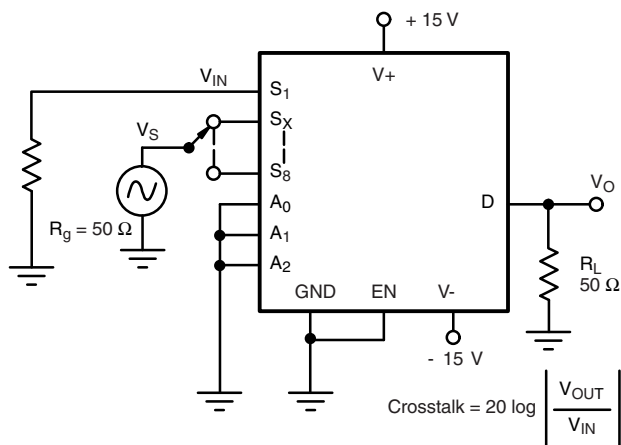
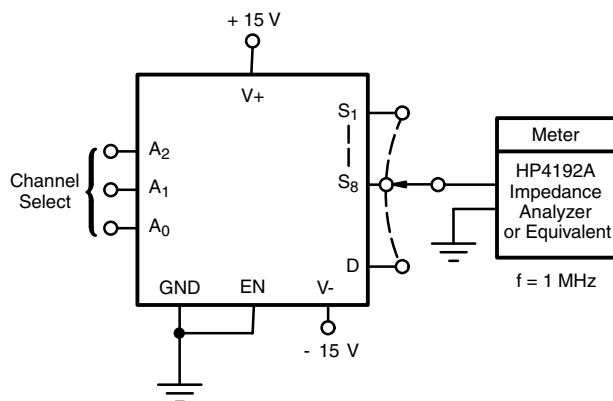
Leakage Current vs. Temperature



Leakage Current vs. Analog Voltage

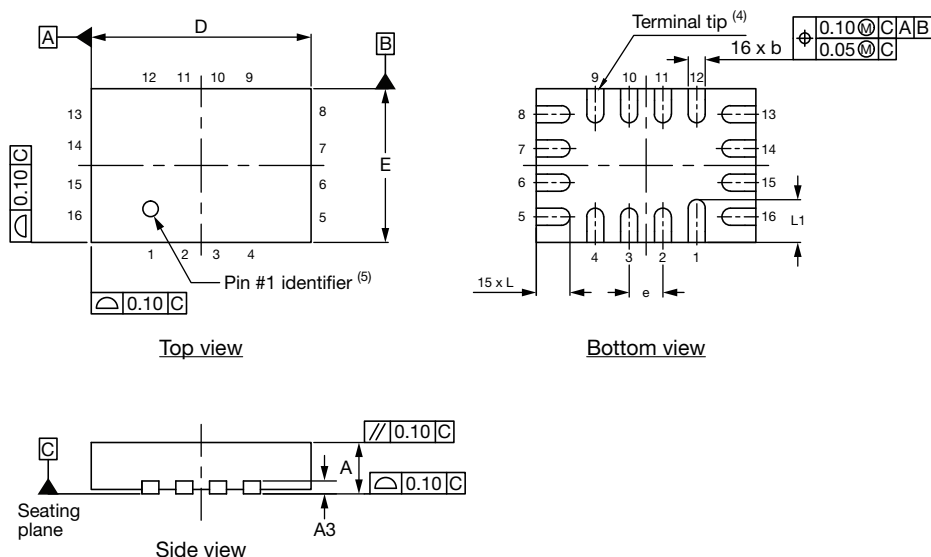
TEST CIRCUITS

Fig. 2 - Transition Time

Fig. 3 - Enable Switching Time

TEST CIRCUITS

Fig. 4 - Break-Before-Make Interval

Fig. 5 - Charge Injection

Fig. 6 - Off Isolation

Fig. 7 - Insertion Loss

TEST CIRCUITS

Fig. 8 - Crosstalk

Fig. 9 - Source Drain Capacitance

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?64821.

Thin miniQFN16 Case Outline



DIMENSIONS	MILLIMETERS ⁽¹⁾			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	0.50	0.55	0.60	0.020	0.022	0.024
A1	0	-	0.05	0	-	0.002
A3	0.15 ref.			0.006 ref.		
b	0.15	0.20	0.25	0.006	0.008	0.010
D	2.50	2.60	2.70	0.098	0.102	0.106
e	0.40 BSC			0.016 BSC		
E	1.70	1.80	1.90	0.067	0.071	0.075
L	0.35	0.40	0.45	0.014	0.016	0.018
L1	0.45	0.50	0.55	0.018	0.020	0.022
N ⁽³⁾	16			16		
Nd ⁽³⁾	4			4		
Ne ⁽³⁾	4			4		

Notes

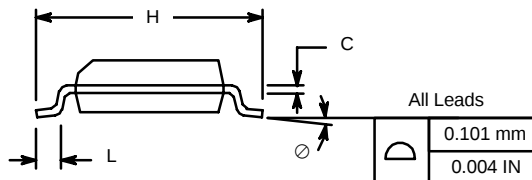
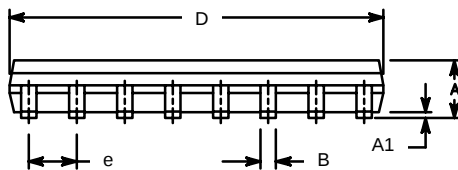
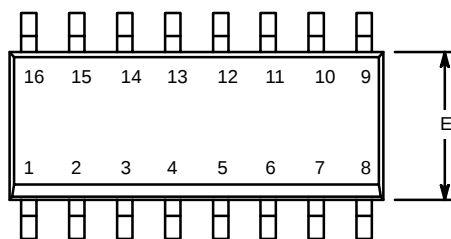
- (1) Use millimeters as the primary measurement.
- (2) Dimensioning and tolerances conform to ASME Y14.5M. - 1994.
- (3) N is the number of terminals. Nd and Ne is the number of terminals in each D and E site respectively.
- (4) Dimensions b applies to plated terminal and is measured between 0.15 mm and 0.30 mm from terminal tip.
- (5) The pin 1 identifier must be existed on the top surface of the package by using identification mark or other feature of package body.
- (6) Package warpage max. 0.05 mm.

ECN: T16-0226-Rev. B, 09-May-16
DWG: 6023



SOIC (NARROW): 16-LEAD

JEDEC Part Number: MS-012

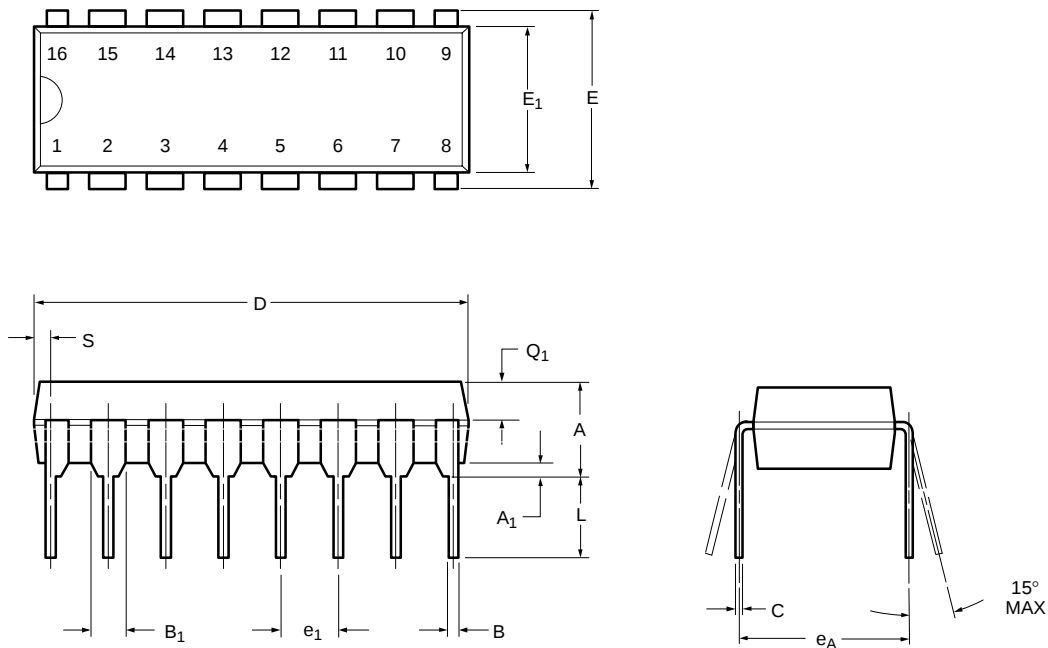


Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	1.35	1.75	0.053	0.069
A ₁	0.10	0.20	0.004	0.008
B	0.38	0.51	0.015	0.020
C	0.18	0.23	0.007	0.009
D	9.80	10.00	0.385	0.393
E	3.80	4.00	0.149	0.157
e	1.27 BSC		0.050 BSC	
H	5.80	6.20	0.228	0.244
L	0.50	0.93	0.020	0.037
Ø	0°	8°	0°	8°

ECN: S-03946—Rev. F, 09-Jul-01
DWG: 5300



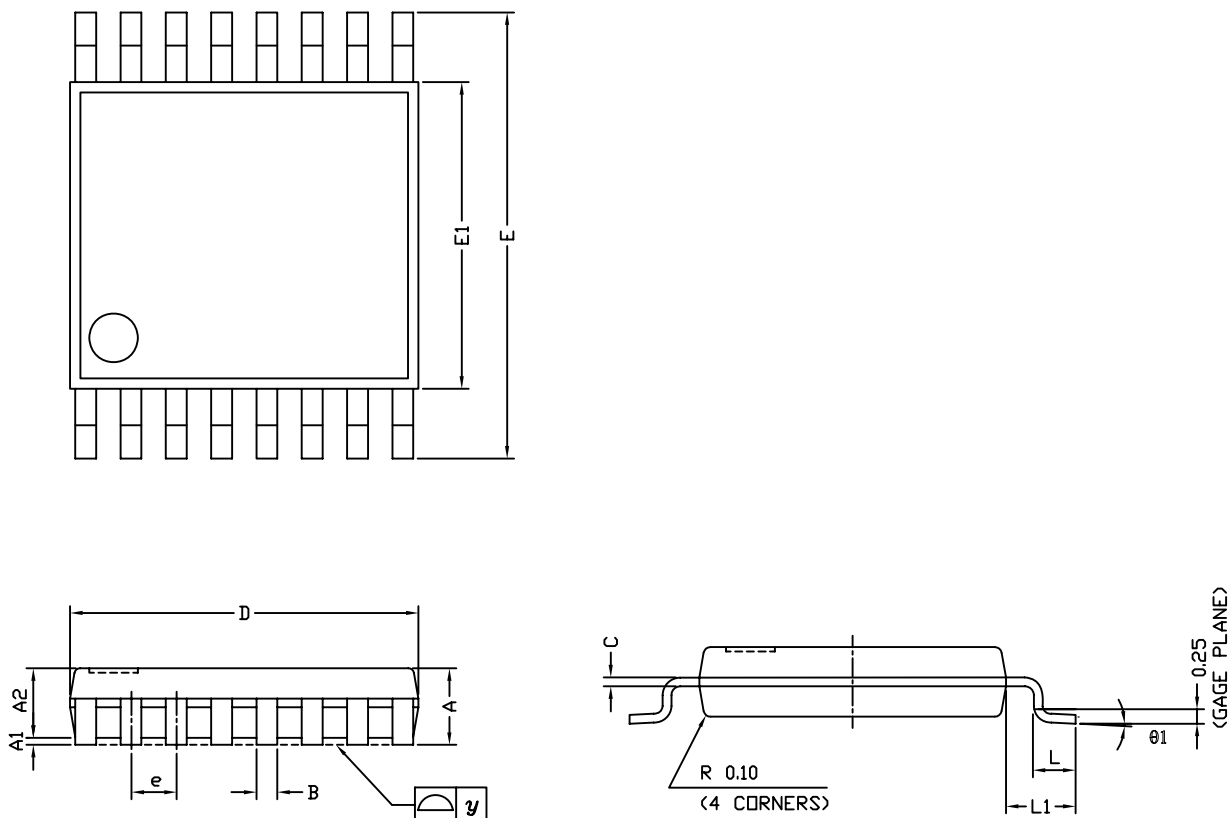
PDIP: 16-LEAD



Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	3.81	5.08	0.150	0.200
A ₁	0.38	1.27	0.015	0.050
B	0.38	0.51	0.015	0.020
B ₁	0.89	1.65	0.035	0.065
C	0.20	0.30	0.008	0.012
D	18.93	21.33	0.745	0.840
E	7.62	8.26	0.300	0.325
E ₁	5.59	7.11	0.220	0.280
e ₁	2.29	2.79	0.090	0.110
e _A	7.37	7.87	0.290	0.310
L	2.79	3.81	0.110	0.150
Q ₁	1.27	2.03	0.050	0.080
S	0.38	1.52	.015	0.060

ECN: S-03946—Rev. D, 09-Jul-01
DWG: 5482

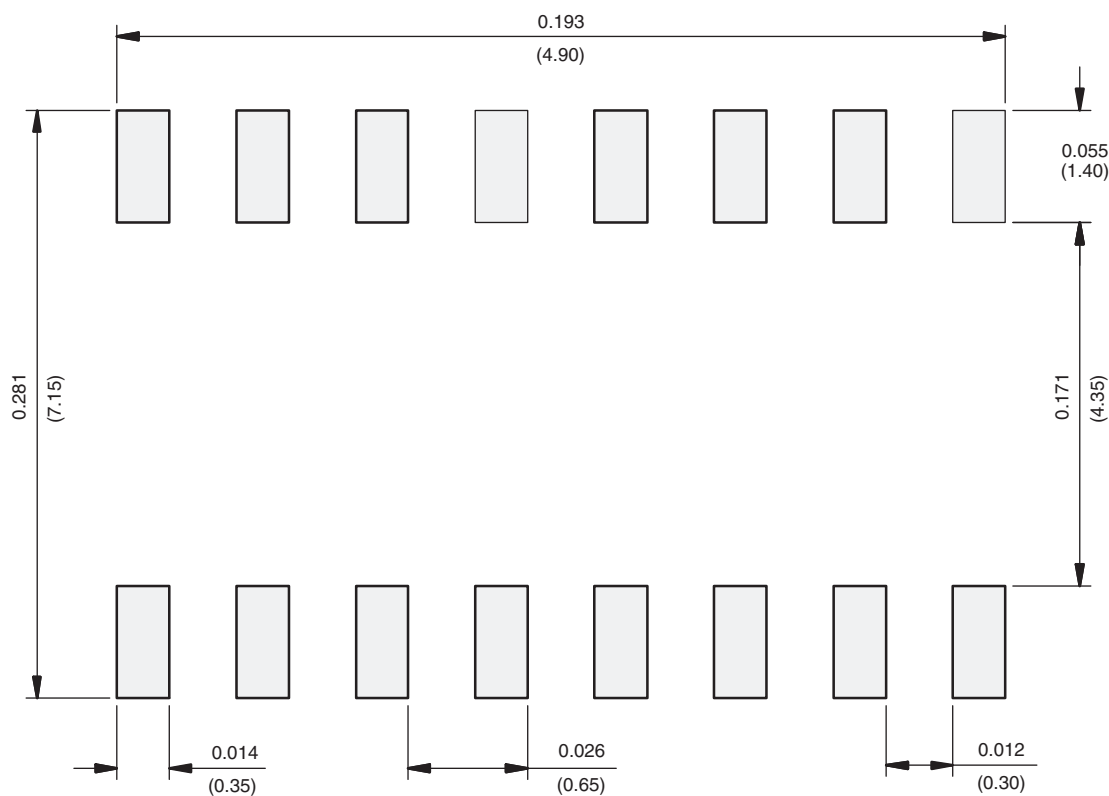
TSSOP: 16-LEAD



Symbols	DIMENSIONS IN MILLIMETERS		
	Min	Nom	Max
A	-	1.10	1.20
A1	0.05	0.10	0.15
A2	-	1.00	1.05
B	0.22	0.28	0.38
C	-	0.127	-
D	4.90	5.00	5.10
E	6.10	6.40	6.70
E1	4.30	4.40	4.50
e	-	0.65	-
L	0.50	0.60	0.70
L1	0.90	1.00	1.10
y	-	-	0.10
θ1	0°	3°	6°
ECN: S-61920-Rev. D, 23-Oct-06			
DWG: 5624			

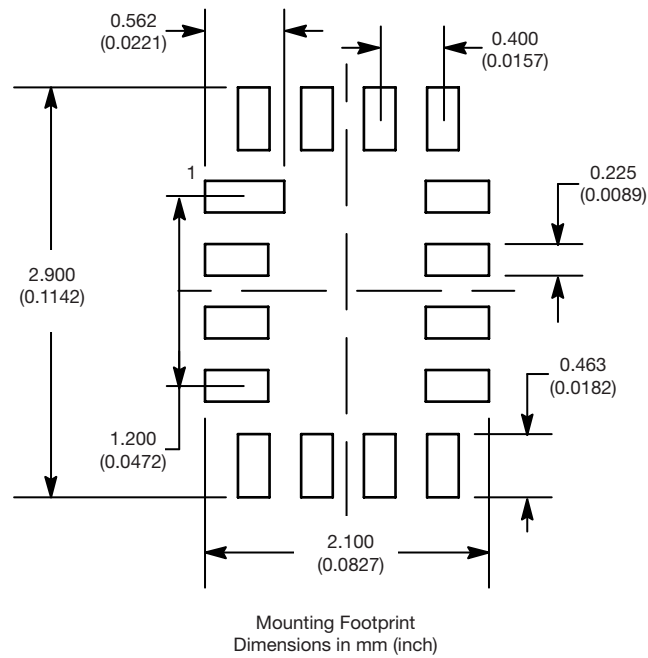


RECOMMENDED MINIMUM PAD FOR TSSOP-16

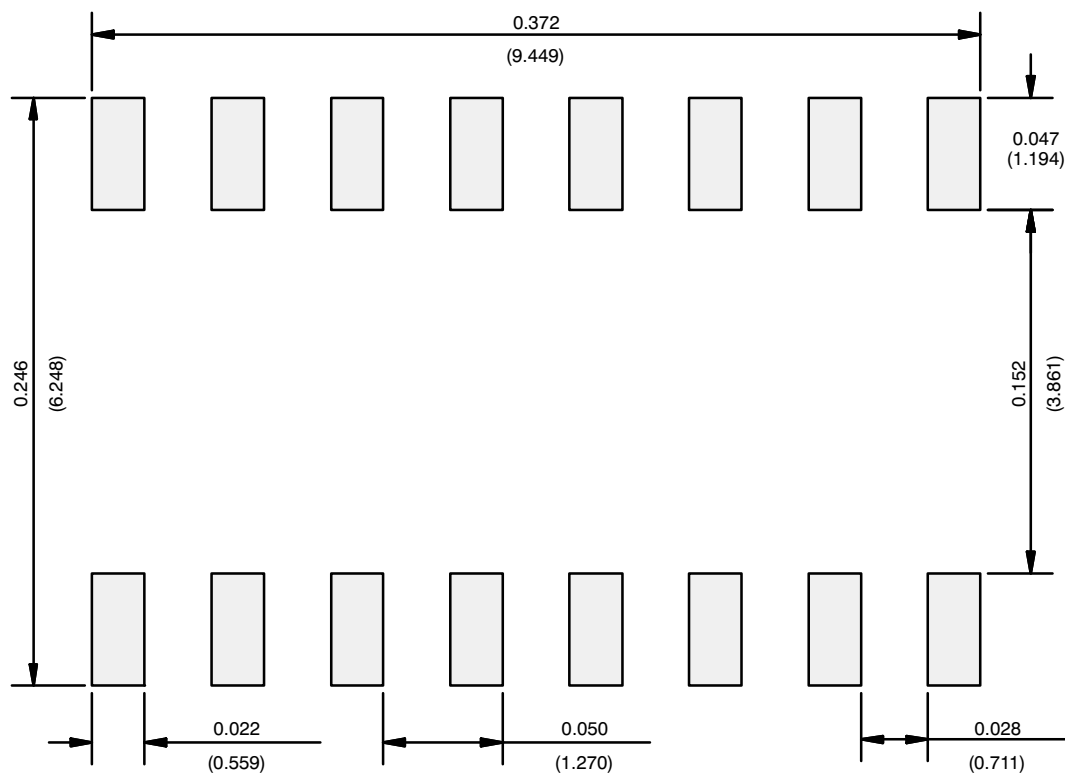


Recommended Minimum Pads
Dimensions in inches (mm)

RECOMMENDED MINIMUM PADS FOR MINI QFN 16L



RECOMMENDED MINIMUM PADS FOR SO-16



Recommended Minimum Pads
Dimensions in Inches/(mm)

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